

BSC0921NDIATMA1

BSC0921NDIATMA1 Information



For Reference Only

Part Number BSC0921NDIATMA1 **Manufacturer** Infineon Technologies

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 30V 17A/31A TISON8

Package 8-PowerTDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BSC0921NDIATMA1 Specifications

Manufacturer Part Number	BSC0921NDIATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	2 N-Channel (Dual) Asymmetrical
FET Feature	Logic Level Gate, 4.5V Drive
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	17A, 31A
Rds On (Max) @ Id, Vgs	5 mOhm @ 20A, 10V
Vgs(th) (Max) @ Id	2V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	8.9nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1025pF @ 15V
Power - Max	1W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-PowerTDFN
Supplier Device Package	PG-TISON-8
	Report errors?

BSC0921NDIATMA1 Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC0921NDIATMA1 Payment Methods



















BSC0921NDIATMA1 Shipping Methods













If you have any question about BSC0921NDIATMA1, please do not hesitate to contact us!

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